## NSN 5962-01-264-3011

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high to low level

View Online at https://aerobasegroup.com/nsn/5962-01-264-3011

Body Leng	th:
0.358 inche	S
Body Widt	n:
0.358 inche	s
Body Heig	nt:
0.100 inche	s
Maximum I	Power Dissipation Rating:
500.0 milliw	atts
Operating	Tempurature Range:
-55.0/+125.	0 degrees celsius
Storage Te	mpurature Range:
-65.0/+150.	0 degrees celsius
Features P	rovided:
Hermeticall	y sealed and burn in and programmable and positive outputs
Inclosure M	faterial:
Ceramic an	d glass
Inclosure (	Configuration:
Leadless fla	it pack
Output Log	jic Form:
Transistor-t	ransistor logic
Input Circu	it Pattern:
16 input	
Case Outli	ne Source And Designator:
C-2 mil-m-3	8510
Current Ra	ting Per Characteristic:
100.00 milli	amperes forward current, peak total value not applicable
Terminal S	urface Treatment:
Solder	
Voltage Ra	ting And Type Per Characteristic:
7.0 volts po	ower source
Time Ratin	g Per Chacteristic:
50.00 nano	seconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time,
output	
Memory De	evice Type:
Pal	
Test Data I	Document:
96906-mil-s	td-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal T	ype And Quantity:
20 leadless	
Shelf Life:	
N/a	
Unit Of Me	asure:

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Demilitarization:

Yes - demil/mli

Fiig:

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